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The Role of Transmission Line Theory in Enhancing Microwave Circuit Performance and Reliability

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Abstract

Microwave circuits are increasingly shaped by the constraints and opportunities imposed by distributed electromagnetic behavior. As frequencies, data rates, and power densities rise, the simple lumped approximations that once sufficed give way to the full logic of propagation, reflection, and radiation embedded in transmission line theory. This paper examines the role of transmission line modeling as a unifying language for performance and reliability in modern microwave systems. It emphasizes how physically faithful per-unit-length parameters, causal dispersion, and network representations enable quantitative control of loss, mismatch, stability, thermal stress, and long-term degradation. The discussion connects line theory to practical architectures such as matching networks, power combiners, couplers, filters, and bias networks, while drawing a direct line from field-circuit synthesis to statistical yield, diagnostics, and design-for-reliability. Beyond steady-state scattering, the analysis addresses waveform integrity, time-domain reflectometry, and calibration strategies that de-embed fixtures and reveal intrinsic device behavior. The paper also integrates electro-thermal coupling, conductor surface physics, and dielectric relaxation into compact, simulation-ready expressions that support robust optimization and verification across manufacturing variability. By making transmission line theory the central scaffold rather than a peripheral tool, designers can reconcile bandwidth and efficiency, reduce sensitivity to process drift, and extend mean time to failure without sacrificing density or cost. The resulting viewpoint is not a collection of formulas but a method of systematically translating electromagnetic structure into predictable microwave function, ultimately improving repeatability, margin, and diagnostic clarity in systems that must operate reliably for years under cyclic environmental and electrical stress.

Introduction

Microwave circuits operate in a regime where signal wavelengths are comparable to or smaller than the physical dimensions of interconnects, components, and passive structures, leading to phenomena that cannot be adequately described by simple lumped-element models [1]. At lower frequencies, the assumption that current and voltage are uniform across a conductors length holds reasonably well, allowing designers to use resistors, capacitors, and inductors to approximate circuit behavior. However, once the frequency increases into the microwave domaintypically above 1 GHzthis assumption collapses. The wavelength becomes short enough that even a few millimeters of transmission line introduce significant phase shift, reflections, and standing waves. As a result, the distributed nature of energy storage and dissipation along guiding structures becomes dominant, and the interaction between electric and magnetic fields must be treated with precision. In such an environment, voltage and current no longer vary uniformly but rather as traveling waves, each subject to propagation delay, attenuation, and phase distortion that arise from the electromagnetic properties of the medium and the geometry of the conductors.

To account for these distributed effects, a theoretical framework is required that incorporates not only the propagation of waves but also the mechanisms that lead to energy loss, modal coupling between conductors, and leakage of energy into free space. Full electromagnetic field solutions based on Maxwells equations provide the most complete description, but they are often too cumbersome for practical circuit analysis and design. Transmission line

Table 1: Distributed vs. Lumped Behavior in Circuits

Regime	Frequency Range	Model Type	Dominant Phenomena	Key Parameters
Low frequency	< 1 GHz	Lumped RLC	Uniform current/voltage	R,L,C constants
Microwave	$1100~\mathrm{GHz}$	Distributed	Wave propagation, reflection	$R(\omega), L(\omega), G(\omega), C(\omega)$
Millimeter-wave	$>100~\mathrm{GHz}$	Full EM field	Dispersion, radiation	Geometry, ϵ_r , μ_r

Table 2: Transmission-Line Theory and Analytical Framework

Concept	Mathematical Tool	Purpose	Physical Basis	Benefit
Telegraphers equations	PDE system	Describe wave propagation	Distributed fields	Predict delay, loss
S-parameters	Matrix formalism	Characterize multiport networks	Power conservation	Enables cascading
Characteristic impedance Z_c	$\sqrt{(R+j\omega L)/(G+j\omega C)}$	Match, reflection control	${\sf Geometry} + {\sf material}$	Design of networks
Propagation constant γ	$\sqrt{(R+j\omega L)(G+j\omega C)}$	Attenuation, phase	Loss + dispersion	Timing prediction

Table 3: Microwave Design Applications and Robustness Factors

Application	Function	Dependent Variables	Sensitivity Source	Mitigation Strategy
Impedance matching	Maximize transfer	Line length, Z_c	Fabrication tolerances	Tuned sections
Couplers / Filters	Signal control	Coupling coeff., ϵ_r	Dielectric variation	Calibration, EM extraction
Power distribution	Uniform feed	Line width, substrate	Temperature, humidity	Thermal design margin
Reliability / Lifetime	Stress localization	Current density, loss	Standing waves, drift	$Causality + passivity \; modeling$

theory bridges this gap by simplifying the electromagnetic problem into a set of manageable equations while still retaining the essential physics. It does so by describing the line in terms of per-unit-length parametersresistance (R), inductance (L), conductance (G), and capacitance (C)that collectively capture the distributed storage and dissipation of energy. These parameters yield the telegraphers equations, which describe how voltage and current waves propagate along the line with finite velocity and frequency-dependent attenuation [2]. This reduction in complexity allows designers to predict the performance of microwave networks while maintaining adherence to the fundamental constraints of causality and passivity, ensuring that the models remain physically meaningful and realizable.

Within this framework, every discontinuity, junction, or transition in a microwave circuit can be interpreted as a boundary-value problem where incident and reflected waves interact. The resulting scattering parameters, or S-parameters, form the language of microwave engineering, allowing the behavior of complex networks to be characterized, cascaded, and optimized using matrix operations. Through this representation, designers can analyze how energy is transmitted, reflected, or absorbed at each port of a device across frequency. Importantly, the use of S-parameters inherently incorporates frequency-dependent effects and ensures energy conservation, making them an ideal analytical tool for high-frequency design. Transmission line theory thus underpins not just the physical understanding of microwave propagation but also the practical computational framework used in simulation and measurement.

When properly formulated, transmission line models serve as the backbone for synthesizing a wide variety of

high-frequency components and subsystems. For example, impedance matching networks rely on transmission line sectionsoften implemented as stubs, transformers, or tapered linesto minimize reflections and maximize power transfer between stages. Similarly, directional couplers exploit controlled coupling between adjacent transmission lines to split or combine signals with defined phase and amplitude relationships. Filters use cascaded line segments and resonators to achieve specific frequency responses, and oscillators and amplifiers depend on feedback networks whose stability and gain characteristics hinge on precise control of transmission line impedances and delays [3]. Even power distribution networks in large systems, such as phased arrays or satellite payloads, depend on transmission line theory to ensure that energy is delivered uniformly and efficiently to multiple paths.

Another critical aspect of microwave circuit design is robustness to variations that occur during fabrication, assembly, and operation. Manufacturing tolerances can alter line widths, substrate thickness, or dielectric constants, while environmental conditions such as temperature changes and humidity can shift material properties and introduce unwanted loss or detuning. Over time, components may experience aging effects that slightly modify electrical performance. A transmission line description that accurately captures the distributed nature of energy flow enables engineers to predict how such perturbations will influence circuit behavior. Because the theory preserves causality and passivity, simulations remain stable and physically valid even when parameters deviate from nominal values. This robustness allows for the design of circuits that maintain their intended performance over wide environmental and operational ranges, an essential requirement in applications such as aerospace communications, radar systems, and wireless infrastructure.

In addition to supporting analytic understanding, transmission line theory informs modern computational tools and numerical solvers. Methods such as the method of moments, finite element analysis, and finite-difference timedomain simulation all rely on transmission line concepts to simplify boundary conditions and to partition complex geometries into manageable segments. Circuit simulators like SPICE, when extended into the microwave domain, use transmission line elements to represent interconnects and distributed networks with delay and frequency-dependent loss [4]. These abstractions allow large systemscombining active devices, passive networks, and distributed interconnections to be modeled efficiently without resorting to fullwave simulation for every detail. As technology progresses into millimeter-wave and terahertz frequencies, this balance between accuracy and tractability becomes increasingly important, enabling engineers to innovate without being overwhelmed by computational complexity.

The elegance of transmission line theory lies in its ability to connect physical intuition with mathematical formalism. The per-unit-length parameters (R, L, G, C) not only correspond to measurable quantities but also provide insight into how geometry and materials influence performance. For example, reducing conductor width increases inductance and characteristic impedance, while increasing substrate permittivity reduces wavelength and compactness at the cost of higher loss. Similarly, the propagation constant and characteristic impedancederived from these parametersdetermine how signals attenuate and phase-shift along the line. By manipulating these quantities, engineers can craft circuits that achieve desired amplitude and phase characteristics over specified bandwidths, ensuring efficient power transfer and minimal signal distortion.

Moreover, the transmission line perspective reveals how energy storage and flow are distributed in space and time. In contrast to lumped circuits where energy is localized in discrete components, microwave circuits exhibit a continuous exchange of energy between electric and magnetic fields along the guiding structure. This interplay gives rise to standing waves, resonances, and impedance transformations that are central to the operation of resonators, antennas, and filters. Understanding these effects enables the deliberate exploitation of interference phenomena for practical functions such as frequency selection, impedance transformation, and signal isolation [5]. Thus, transmission line theory not only simplifies but also enriches the understanding of how electromagnetic energy behaves in engineered structures.

Reliability in microwave systems depends on the integrity of metallization under high current density, the stability of dielectric properties with moisture uptake and temperature cycling, and the risk of localized heating due to standing waves and current crowding at discontinuities. By treating mismatch, dispersion, and dissipation as coupled

phenomena that live on the same distributed scaffold, it becomes possible to identify the spatial and spectral loci of stress, to quantify their sensitivity to geometry and material variations, and to design structures whose worst-case excursions remain within safe operating areas. This perspective converts transmission line theory from a means of calculating S-parameters into a predictive physics engine for lifetime and yield.

At the circuit-network interface, line theory supplies matrix mappings between traveling-wave variables and lumped ports. These mappings preserve power flow and enable stability analyses that recognize feedback loops formed by interconnects as much as by active devices. The classical intuition of return loss and voltage standing wave ratio only becomes actionable in real systems when embedded within line-aware multiport models that honor electromagnetic reciprocity where it applies, capture nonreciprocal biasing where it does not, and remain numerically well-conditioned across broad frequency spans. In practice, the choice of representation determines the transparency with which constraints such as passivity, causality, and realizability can be enforced during synthesis and model order reduction.

The same theory governs instrumentation. Calibration strategies, from thru-reflect-line to line-reflect-match, rely on known transmission line segments to anchor phase and magnitude, revealing the internal error boxes of a measurement setup. Time-domain techniques interpret backscattered waveforms through the lens of reflections on a line, allowing the resolution of subwavelength defects and the extraction of local impedance profiles. When these diagnostic methods feed back into design, they close the loop between predicted fields, measured network responses, and the microphysical mechanisms that determine performance drift over time.

Finally, transmission line theory acts as a bridge between numerical electromagnetics and circuit simulation. Per-unit-length parameter extraction condenses field solutions into frequency-dependent R, L, G, and C operators that retain dispersion and anisotropy, while macromodeling strategies approximate these operators by rational functions suitable for transient simulation. With appropriate constraints to guarantee passivity and causality, the resulting models become drop-in elements of system-level verification that capture waveform distortion, intermodulation, and electro-thermal feedback with predictive fidelity. In what follows, the paper develops these themes in depth, demonstrating how transmission line theory enhances both the performance metrics and the reliability envelope of microwave circuits.

Fundamentals of Distributed Modeling and Energy Flow

A transmission line abstracts a guiding structure by per-unit-length parameters that encode electromagnetic storage and dissipation. In the most general quasi-

static form for a two-conductor line, the longitudinal voltage and current satisfy a pair of first-order partial differential equations in space and time that encapsulate the interplay of inductive and capacitive storage with resistive and conductive loss. From these equations, propagation emerges as a consequence of distributed inertia and compliance, while attenuation and phase dispersion follow from the frequency dependence of the underlying operators. The characteristic impedance and propagation constant, defined as functions of frequency and geometry, are the principal macroscopic descriptors of the line, while local power flow and energy density connect directly to these descriptors. [6]

$$\frac{\partial v(z,t)}{\partial z} = -r(\partial_t) i(z,t) - l(\partial_t) \frac{\partial i(z,t)}{\partial t},$$

$$\frac{\partial i(z,t)}{\partial z} = -g(\partial_t) v(z,t) - c(\partial_t) \frac{\partial v(z,t)}{\partial t} \tag{1}$$

Under steady-state sinusoidal excitation at angular frequency ω , the frequency-domain telegrapher system reduces to algebraic relations involving complex per-unit-length parameters $R(\omega),\,L(\omega),\,G(\omega),\,C(\omega)$ that encode skin effect, dielectric relaxation, and radiation loading. The propagation constant $\gamma(\omega)=\alpha(\omega)+j\beta(\omega)$ and characteristic impedance $Z_0(\omega)$ emerge by eliminating spatial derivatives, revealing the hyperbolic dependence of input impedance and transfer functions on length. These quantities determine both how signals traverse the line and how standing waves form between discontinuities.

$$\gamma(\omega) = \sqrt{\left(R(\omega) + j\omega L(\omega)\right)\left(G(\omega) + j\omega C(\omega)\right)},$$

$$Z_0(\omega) = \sqrt{\frac{R(\omega) + j\omega L(\omega)}{G(\omega) + j\omega C(\omega)}}$$
(2)

Energy and power relations follow from Poynting vector integrals reduced to line variables. The average power carried by a forward traveling wave is the product of the squared wave amplitude and the real part of the characteristic admittance [7]. This description preserves passivity and links attenuation directly to the work done against resistive and dielectric loss per unit length, grounding performance metrics such as insertion loss in a physical accounting of dissipation.

$$P_{+}(\omega) = \frac{1}{2} |V_{+}(\omega)|^{2} \Re\{Y_{0}(\omega)\}, \quad Y_{0}(\omega) = \frac{1}{Z_{0}(\omega)}$$

Generalization to multiconductor structures introduces matrix-valued per-unit-length parameters. Modal decomposition diagonalizes these matrices where symmetry and boundary conditions permit, but coupling often persists due to proximity, anisotropy, or intentional periodic loading. The resulting vector telegrapher equations propa-

gate multiple modes with distinct velocities and attenuations, capturing crosstalk, mode conversion, and bandedge phenomena associated with periodicity. This framework integrates seamlessly with network theory by associating traveling-wave vectors at ports with incident and reflected power-normalized quantities, enabling concise expressions for interactions between distributed interconnects and lumped or active elements.

$$\frac{d}{dz} \begin{bmatrix} \mathbf{V}(z,\omega) \\ \mathbf{I}(z,\omega) \end{bmatrix} = - \begin{bmatrix} \mathbf{0} & \mathbf{Z}(\omega) \\ \mathbf{Y}(\omega) & \mathbf{0} \end{bmatrix} \begin{bmatrix} \mathbf{V}(z,\omega) \\ \mathbf{I}(z,\omega) \end{bmatrix},
\mathbf{Z}(\omega) = \mathbf{R}(\omega) + j\omega \mathbf{L}(\omega), \quad \mathbf{Y}(\omega) = \mathbf{G}(\omega) + j\omega \mathbf{C}(\omega)$$
(3)

Causality and passivity impose analytic structure on $\gamma(\omega)$ and $Z_0(\omega)$, expressing KramersKronig relations between their real and imaginary parts. Rational macromodels that respect these constraints can be fitted to field-extracted or measured data and embedded in time-domain simulation without violating energy conservation. The resulting time-domain equations show dispersion by convolution kernels derived from the frequency dependence of the per-unit-length models, yet remain computationally efficient due to state-space realizations.

$$\hat{Z}_0(\omega) \approx \sum_{k=1}^N \frac{a_k}{j\omega - p_k} + d, \quad \hat{\gamma}(\omega) \approx \sum_{k=1}^N \frac{b_k}{j\omega - q_k} + e$$

Transmission Line Foundations for Impedance-Controlled Coaxial and Quasi-Coaxial PCB Structures

Transmission line theory forms the foundational backbone of microwave engineering because it converts the full vectorial complexity of electromagnetic fields into a compact set of distributed parameters that directly govern wave propagation, energy transfer, and dissipation. In media spanning canonical coaxial cables, substrate-integrated waveguides, cavity-backed traces, and quasi-coaxial via transitions, characteristic impedance and the complex propagation constant dictate how efficiently power moves between active and passive subsystems in radar front-ends, satellite transponders, and dense wireless access networks. As operating bands climb into multi-gigahertz regimes and beyond, wavelengths shrink to the scale of board features and package geometries, making percent-level perturbations in dimensions, copper surface condition, or dielectric composition translate into measurable deviations in return loss, group delay, and in-band flatness [8]. Precise impedance control therefore becomes not an optional flourish but a precondition for maintaining link budgets, spectral compliance, and stability margins under environmental cycling and long-term aging. Analytical formulas that balance material properties with geometric configurations provide the designer with transparent levers and sensitivities, enabling fast, verifiable iteration before resorting to full-wave numerics. This same analytic clarity carries into printed circuit analogs of coaxial structures where inner and outer conductors are realized by plated barrels, anti-pads, and stitching via fences, and where logarithmic radius ratios remain the primary geometric knob for tuning characteristic impedance. Such approaches align naturally with ongoing research in via optimizations and pad-stack tailoring for high-density interconnects, as noted in Tsintsadze et al. (2025) [9].

A uniform coaxial line offers a canonical reference because it supports a true transverse electromagnetic mode without cutoff and admits quasi-static closed-form relations for per-unit-length storage and loss. With inner radius a, outer radius b, permeability μ , permittivity $\epsilon = \epsilon_0 \epsilon_r$, and conductor conductivity σ , the familiar quasi-static relations isolate geometry from materials for energy storage while collecting frequency-dependent dissipation in separate terms. The sensitivity of characteristic impedance to the geometry enters through a log-ratio, so dimensioning tasks reduce to choosing (a,b) that realize a target impedance while honoring manufacturing limits and plating allowances. The basic descriptors can be written compactly as

$$L' = \frac{\mu}{2\pi} \ln\left(\frac{b}{a}\right), \quad C' = \frac{2\pi\epsilon}{\ln\left(\frac{b}{a}\right)}, \quad Z_0 = \sqrt{\frac{L'}{C'}} = \frac{60}{\sqrt{\epsilon_r}} \ln\left(\frac{b}{a}\right)$$

with dissipation entering through conductor and dielectric loss contributions [10]

$$R'(\omega) \approx \frac{1}{2\pi} \left(\frac{R_s(\omega)}{a} + \frac{R_s(\omega)}{b} \right),$$

$$G'(\omega) \approx \omega C' \tan \delta,$$

$$R_s(\omega) = \sqrt{\frac{\omega \mu}{2\sigma}}$$
(4)

and the propagation constant

$$\gamma(\omega) = \alpha(\omega) + j\beta(\omega) = \sqrt{\left(R'(\omega) + j\omega L'\right)\left(G'(\omega) + j\omega C'\right)}.$$

In the low-loss regime where $R'\ll \omega L'$ and $G'\ll \omega C'$, the standard approximations decouple attenuation and phase to first order,

$$\alpha(\omega) \approx \frac{R'(\omega)}{2Z_0} + \frac{G'(\omega)Z_0}{2},$$

$$\beta(\omega) \approx \omega \sqrt{L'C'},$$

$$v_g^{-1} = \frac{d\beta}{d\omega} \approx \sqrt{L'C'}$$
(5)

These relations expose a central design trade: for fixed ϵ_r , increasing the log-ratio $\ln(b/a)$ raises Z_0 , lowers C', raises L', and shifts the relative weighting of conductor and dielectric losses in $\alpha(\omega)$ [11]. Because both R' and

G' depend on geometry and materials in distinct ways, achieving a target insertion loss across a band is an optimization in a small, interpretable space.

Impedance control tolerances follow directly from differentiating the analytic form of Z_0 . For small perturbations,

$$\frac{\partial Z_0}{\partial a} = -\frac{60}{\sqrt{\epsilon_r}} \frac{1}{a \ln(\frac{b}{a})},$$

$$\frac{\partial Z_0}{\partial b} = +\frac{60}{\sqrt{\epsilon_r}} \frac{1}{b \ln(\frac{b}{a})},$$

$$\frac{\partial Z_0}{\partial \epsilon_r} = -\frac{30}{\epsilon_r^{3/2}} \ln(\frac{b}{a})$$
(6)

so fractional errors in the smaller radius a weigh more heavily than equal absolute errors in b. Converting a geometry tolerance into an impedance tolerance and then into a reflection budget is straightforward using $\Gamma=(Z_2-Z_1)/(Z_2+Z_1)$. If the design requires $\pm 5\%$ impedance control around a nominal Z_0 , the small-signal reflection amplitude per step is about $|\Gamma|\approx |\Delta Z|/(2Z_0) \leq 2.5\%$, a value that can then be phased and summed across multiple discontinuities to bound ripple in $|S_{21}|$ and group delay over operating bands. In broadband radar and modern high-order wireless modulations, those ripple metrics directly influence pulse compression sidelobes and error vector magnitude, motivating line-by-line conversion of mechanical tolerances into electrical ripple allocations.

Quasi-coaxial behavior within printed circuit boards extends coaxial intuition to practical interconnect topologies. Plated-through via barrels with anti-pad clearances and surrounding ground stitching vias form an approximate cylindrical field enclosure for the current flowing between reference planes. A first-order effective-medium model retains the log-ratio dependence,

$$Z_{\rm via} \approx \frac{60}{\sqrt{\epsilon_{\rm eff}}} \ln\!\left(\frac{r_c}{r_v}\right), \qquad \epsilon_{\rm eff} \approx \eta \, \epsilon_{r, \rm core} + (1-\eta) \cdot 1, \label{eq:Zvia}$$

where r_v is the via barrel radius, r_c is an effective clearance radius shaped by anti-pad geometry and copper pullbacks, and $\eta \in (0,1)$ is a fill factor reflecting the mixture of dielectric and air in the local field aperture. While full-wave extraction is essential for final verification, these expressions provide rapid early-stage sizing of anti-pads and pad stacks to place the via impedance near the line impedance it must join [12]. This analytic approach also dovetails with contemporary pad-stack and via-field optimizations documented in recent literature, including via shaping and antipad eccentricity control to balance power integrity and RF performance. Because any impedance step gives rise to reflection, carefully shaped transitions are deployed to bridge unavoidable differences with minimal penalty. Treating the characteristic impedance as a slowly varying function Z(z)along a taper of length ℓ yields a first-order reflection estimate via a WKB-like integral,

$$\Gamma(\omega) \approx \frac{1}{2} \int_0^\ell \frac{d}{dz} \ln Z(z) \exp(-2j\beta(\omega)z) dz,$$

from which classical exponential and Klopfenstein profiles are derived by bounding $|\Gamma|$ over a band. When the local cross-section remains coaxial-like, the taper can be parametrized by b(z)/a(z), translating mechanical constraints and anti-pad rules into a directly optimizable Z(z). In short transitions where electrical length is constrained, the integrals stationary points indicate where shaping effort buys the largest reflection reduction, and those points typically coincide with spots where fields concentrate and thermal margins are thinnest, linking performance to reliability.

Periodicity and confinement details of quasi-coaxial fences introduce weak band-structure effects that can be captured by cell transfer matrices. When via pitch approaches a non-negligible fraction of the guided wavelength, the effective medium acquires stopbands and a Bloch impedance replaces a purely local Z_0 . Still, the dominant control remains the enclosure strength and symmetry imposed by the via fence and plane apertures. A cell description makes this concrete: [13]

$$\cos\left(\beta a\right) = \frac{A_{\rm cell}(\omega) + D_{\rm cell}(\omega)}{2}, \qquad Z_B(\omega) = \sqrt{\frac{B_{\rm cell}(\omega)}{C_{\rm cell}(\omega)}},$$

with $A_{\rm cell}, B_{\rm cell}, C_{\rm cell}$, $D_{\rm cell}$ the ABCD parameters of one periodic segment. Keeping a sufficiently small and designing the anti-pad contours to limit higher-order mode excitation preserves a quasi-TEM fundamental that behaves like a gently dispersive coaxial line.

Surface physics matters at gigahertz frequencies because it modifies conductor loss via an effective roughness factor $\kappa_r(\omega) \geq 1$ that multiplies the classical skin-effect surface resistance. A compact attenuation partition illustrates the competing levers:

$$R_s^{\rm eff}(\omega) = \kappa_r(\omega) \sqrt{\frac{\omega \mu}{2\sigma}}, \qquad \alpha_c(\omega) \approx \frac{1}{2Z_0} \left(\frac{1}{2\pi} \left(\frac{R_s^{\rm eff}}{a} + \frac{R_s^{\rm eff}}{b} \right) \right)$$

For a given target Z_0 and run length ℓ , one can minimize the band-averaged insertion loss by co-selecting ϵ_r and $\ln(b/a)$ subject to fabrication constraints. As ϵ_r decreases, the same Z_0 demands a larger b/a, which reduces C' and increases L', shifting conductor versus dielectric attenuation contributions. This trade can be cast as a constrained optimization,

$$\min_{a,b,\epsilon_r} \ \int_{\Omega} \left(\frac{R'(\omega)}{2Z_0(a,b,\epsilon_r)} + \frac{G'(\omega)Z_0(a,b,\epsilon_r)}{2} \right) \, d\omega$$

subject to the impedance constraint $Z_0-60\ln(b/a)/\sqrt{\epsilon_r}=0$ and geometric bounds that represent drill, plating, and laminate rules. The gradients implied by the analytic formulas enable direct, fast convergence and also serve as sensitivity measures for process capability studies.

Group delay dispersion couples directly to waveform integrity in phase-coherent systems. For low-loss TEM-like structures, dispersion arises mainly through the weak

frequency dependence of ϵ_r and the effective permittivity of composite apertures. The group delay per length is [14]

$$\tau_g'(\omega) = \frac{d\beta}{d\omega}$$

$$= \sqrt{L'(\omega)C'(\omega)} + \frac{\omega}{2} \frac{d}{d\omega} (L'(\omega)C'(\omega)) / \sqrt{L'(\omega)C'(\omega)}$$
(7)

so stabilizing $\epsilon_{\rm eff}(\omega)$ by maintaining consistent cavity geometry and closely spaced return fences improves phasedarray beam squint and digital communications eye openings across temperature and humidity excursions. In practice, this means keeping anti-pad shapes and via pitches uniform through z-height, which also eases calibration and de-embedding because the effective medium remains stationary along the frequency axis.

Transition regions between external coaxial interfaces and internal planar or quasi-coaxial board structures are recurring sources of mismatch and mode conversion. A practical synthesis trick is to trace a virtual path from the cylindrical connector fields to the planar or via-field aperture and enforce a nearly constant local impedance profile along that path. The local impedance can be modeled by a smoothly varying log-ratio that maps to physical flares and anti-pad gradients,

$$Z_{\rm local}(s) \approx \frac{60}{\sqrt{\epsilon_{\rm eff}(s)}} \ln\!\left(\frac{b(s)}{a(s)}\right), \label{eq:Zlocal}$$

shape
$$a(s), b(s)$$
 : $\left| \frac{d}{ds} \ln Z_{\text{local}}(s) \right|$ small (8)

which, when combined with the WKB reflection integral, yields an explicit bound on $|\Gamma|$ over the band for a given transition length L. If mechanical constraints force very short transitions, of the reflection optimization searches within the constraints \mathbb{Z} manifold provide the closest realizable approximation to a reflectionless transformer.

Multilayer stacks complicate the picture because vias traverse dielectrics with different ϵ_r , thicknesses, and copper clearances, producing cascaded sections with distinct Z_{0k} and γ_k . A transmission-line cascade treats each segment as uniform and composes input impedance by the hyperbolic formula,

$$Z_{\text{in}}^{(k)} = Z_{0k} \frac{Z_{\text{in}}^{(k+1)} + Z_{0k} \tanh(\gamma_k \ell_k)}{Z_{0k} + Z_{\text{in}}^{(k+1)} \tanh(\gamma_k \ell_k)}, \qquad Z_{\text{in}}^{(N)} = Z_L,$$

which predicts small resonances and group delay ripple caused by residual stubs [15]. Back-drilling reduces unused stub length ℓ_{stub} , pushing quarter-wave notches away from the band of interest,

$$f_{
m notch} pprox rac{c}{4\sqrt{\epsilon_{
m eff}}\,\ell_{
m stub}},$$

$$|\Gamma_{
m stub}(\omega)| pprox \left| rac{jZ_0 anig(eta(\omega)\ell_{
m stub}ig)}{2Z_0 + jZ_0 anig(eta(\omega)\ell_{
m stub}ig)}
ight| \qquad (9)$$

Specifying a maximum allowable in-band ripple yields a bound on $\ell_{\rm stub}$ that can be made robust by tightening with respect to ϵ_r drift over temperature and moisture absorption. This is exactly the kind of practical, geometry-to-spec linkage that the line abstraction makes algebraically tractable early in design.

Sensitivity and yield assessments inherit the same transparency. Differentiating $Z_{\rm in}$ and Γ with respect to geometric parameters θ_i and combining with fabrication variances gives first-order predictions of performance spread,

$$\frac{\partial \Gamma}{\partial \theta_i} \approx \frac{1}{2Z_0} \frac{\partial Z_{\mathsf{in}}}{\partial \theta_i}, \qquad \mathrm{Var}[\, \Gamma(\omega) \,] \approx \sum_i \left(\frac{\partial \Gamma(\omega)}{\partial \theta_i} \right)^2 \mathrm{Var}[\theta_i],$$

which can be integrated over frequency with appropriate weighting to match system-level figures of merit. Importantly, the same derivatives also identify which tolerances dominate electrical variability, guiding metrology and process control to the handful of dimensionsoften the inner barrel radius, anti-pad minor axis, or back-drill depththat truly matter.

It is instructive to contrast coaxial and quasi-coaxial lines with hollow metallic waveguides employed at higher microwave and millimeter-wave frequencies. In single-mode TE or TM bands, propagation exhibits cutoff and strong dispersion, with

$$eta(\omega) = \sqrt{\omega^2 \mu \epsilon - k_c^2}, \qquad Z_{0, {\sf TE}} = rac{\omega \mu}{eta}, \qquad Z_{0, {\sf TM}} = rac{eta}{\omega \epsilon},$$

so the characteristic impedance and group delay vary with frequency in ways that complicate broadband matching. Yet the transmission-line vocabulary persists: one still works with $Z_0(\omega)$ and $\gamma(\omega)$, designs tapers to bound $|\Gamma|$, and assigns ripple budgets. Mixed media systems that transition between coaxial feeds, planar interposers, and waveguide filters benefit from a common framework in which each segment is a line with its own $Z_0(\omega)$ and $\gamma(\omega)$, and interfaces are engineered to keep the composite reflection profile below budget while distributing thermal and electric field stress benignly. [16]

Reliability enters naturally because the same variables that deliver performance also set current density and electric field maxima. Under skin effect, current crowds at conductor surfaces with magnitude $J\sim I/(2\pi r\delta)$, peaking on the inner conductor of a coaxial cross-section. For fixed power P, raising Z_0 increases line voltage and reduces current, shifting stress from conductor heating toward dielectric field stress. A quantitative balance follows from

with $P=(|V^+|^2/2)\Re\{Y_0\}=(|I^+|^2/2)\Re\{Z_0\}$. Choosing (a,b,ϵ_r) to meet an impedance target while keeping $E_{\rm max}$ and $J_{\rm max}$ under material and plating limits becomes a tractable multi-criteria exercise, and the derivatives of these stress measures with respect to geometry guide where copper thickness, surface finish, or anti-pad smoothing buys the greatest margin. Because material properties vary with temperature, small-signal electro-thermal linearization adds another layer,

$$\frac{dZ_0}{dT} = \frac{\partial Z_0}{\partial \epsilon_r} \frac{d\epsilon_r}{dT} + \frac{\partial Z_0}{\partial a} \frac{da}{dT} + \frac{\partial Z_0}{\partial b} \frac{db}{dT},$$

$$\frac{d\alpha}{dT} \approx \frac{1}{2Z_0} \frac{dR'}{dT} + \frac{Z_0}{2} \frac{dG'}{dT} - \frac{\alpha}{Z_0} \frac{dZ_0}{dT} \tag{11}$$

which links environmental cycling to electrical drift and, ultimately, to lifetime predictions under mission profiles.

Measurement and diagnostics are equally grounded in line concepts. Time-domain reflectometry interprets measured voltage ratios through a spatially varying reflection coefficient, [17]

$$\Gamma(z) \approx \mathcal{F}^{-1} \left\{ \frac{V_{\text{meas}}(\omega)}{V_{\text{src}}(\omega)} \, e^{2j\beta(\omega)z} \right\},\,$$

which, when combined with a calibrated $\beta(\omega)$ for the quasicoaxial medium, maps ripple back to locations in the padstack or via field with sub-wavelength resolution. Thrureflect-line calibration uses known line sections to anchor phase and magnitude, and de-embedding composes and inverts line-based fixtures to reveal intrinsic device responses. Because all of these steps use the same $Z_0(\omega)$ and $\gamma(\omega)$ extracted during design, the loop between prediction and observation is tight, enabling rapid correction of dimensional drifts or laminate substitutions.

Finally, the role of transmission line theory in system partitioning cannot be overstated. In wideband active arrays and multi-standard radios, budgets for reflection, insertion loss, and group delay ripple are allocated across dozens of concatenated elements. A coaxial-like via transition that keeps mismatch under a few percent and attenuation within a fraction of a decibel per inch relaxes demands on the power amplifier and improves noise figure headroom in the receive chain. Conversely, a poorly controlled pad-stack that behaves as a short stub can introduce a narrow notch or phase kink that degrades beamforming or corrupts equalizer assumptions. Because the formulas governing these outcomes remain compact and differentiable, they are amenable to inclusion in automated synthesis and tolerance-to-yield flows, producing designs that are both high-performing and robust. In this sense, classical equationsparticularly those governed by logarithmic radius ratios in coaxial and quasi-coaxial geometriesremain essential tools in modern practice, providing the analytic scaffolding that underlies numerical verification and guides practical improvements in via-field shaping and anti-pad optimization strategies highlighted in Tsintsadze et al. (2025) [9].

Network Representations, Matching, and Stability

Microwave circuits composed of distributed segments and lumped or active elements are conveniently described using scattering matrices whose entries relate incident and reflected wave amplitudes referenced to real characteristic impedances. Transmission lines act as tunable delay and impedance transformers, so the mapping between local port impedances determines reflection and transmission with exponential sensitivity to electrical length near Matching strategies, whether narrowband or broadband, become problems of shaping the complex trajectory of the input reflection coefficient as a function of frequency to meet specifications on magnitude and phase while accommodating realizable element constraints.

$$\mathbf{b}(\omega) = \mathbf{S}(\omega)\,\mathbf{a}(\omega), \quad a_k = \frac{V_k + I_k Z_{0k}}{2\sqrt{Z_{0k}}}, \quad b_k = \frac{V_k - I_k Z_{0k}}{2\sqrt{Z_{0k}}}$$

Cascading networks benefits from ABCD (transmission) matrices, which multiply along the signal path and admit closed-form expressions for uniform line sections. Conversions between representations preserve power waves and facilitate synthesis by localizing constraints. For a uniform line of length l, the ABCD description expresses both delay and transformation in terms of hyperbolic functions of the propagation constant and characteristic impedance, revealing the sensitivity of impedance seen at one end to load variations at the other as electrical length approaches quarter- or half-wavelength conditions.

$$\begin{bmatrix} A & B \\ C & D \end{bmatrix} = \begin{bmatrix} \cosh(\gamma l) & Z_0 \sinh(\gamma l) \\ \sinh(\gamma l)/Z_0 & \cosh(\gamma l) \end{bmatrix}$$

Matching over finite bands can be cast as an optimization that minimizes the supremum of the reflection coefficient under constraints derived from realizability and loss budgets. By approximating the frequency dependence with rational bases and imposing positivity on energy storage operators, one obtains convex relaxations that yield nearoptimal networks [18]. Robust formulations incorporate uncertainty in per-unit-length parameters and component tolerances, ensuring that the worst-case reflection remains within targets even under drift. Weighted norms accommodate the different importance of sub-bands for system-level metrics like error vector magnitude or adjacent channel leakage.

$$\min_{\theta} \max_{\omega \in \Omega} |\Gamma_{\mathsf{in}}(\omega; \theta)| \quad \mathsf{subject to} \ \mathcal{R}(\theta) \succeq 0, \ \mathcal{C}(\theta) \succeq 0, \ \mathcal{L}(\theta) \succeq$$

Stability metrics for amplifier-line combinations, including Rolletts factor and related measures, depend explicitly on the embedding network. Transmission lines introduce frequency-selective feedback via round-trip delay and frequency-dependent loading, modifying the loci where the loop transmission crosses unity gain with nonzero phase. Stability assessment thus benefits from views that keep the line explicitly in the loop rather than collapsing it to a constant element. Delays can be represented in rational form via Padé approximants or stored directly in time-domain solvers; either way, the stability margins become functions of both load reflection and phase winding supplied by interconnect.

$$k = \frac{1 - |S_{11}|^2 - |S_{22}|^2 + |\Delta|^2}{2|S_{12}S_{21}|}, \quad \Delta = S_{11}S_{22} - S_{12}S_{21}$$

Power combining and splitting networks exemplify how lines shape performance tradeoffs. In Wilkinson and hybrid structures, equal-amplitude, phase-controlled paths exploit quarter-wave transformations and isolation resistors that dissipate only imbalance energy. The achievable bandwidth, isolation, and insertion loss are coupled through the line dispersion and dissipation; optimizing these quantities requires models that accurately capture both the amplitude and phase of $Z_0(\omega)$ and $\gamma(\omega)$ under thermal and bias-induced shifts. Similarly, filter topologies realized as cascaded or coupled resonators translate transmission line stubs and coupled sections into polezero placements whose sensitivity to geometry and material parameters is governed by the same distributed descriptors, ensuring that reliability considerations enter at synthesis time rather than as afterthoughts.

Loss Mechanisms, Dispersion, and Material Physics

Loss in microwave transmission lines arises from several interacting physical mechanisms that dissipate or radiate electromagnetic energy as a signal propagates along the line [19]. Fundamentally, these losses originate in the finite conductivity of the metallic conductors, the nonzero loss tangent of the dielectric materials that support and separate those conductors, and the possibility of energy leakage into modes that are not bound to the guiding structure. In a well-designed microwave interconnect or component, each of these effects can be minimized but never completely eliminated, and accurate modeling is required to predict performance across wide frequency ranges. Because microwave circuits operate in regimes where both electromagnetic field distributions and material properties vary strongly with frequency, empirical approximations are insufficient for precision design. Instead, causal, frequency-dependent models of per-unit-length resistance, inductance, conductance, and capacitance must be derived from geometry and materials $\min_{\theta} \max_{\omega \in \Omega} |\Gamma_{\text{in}}(\omega;\theta)| \quad \text{subject to } \mathcal{R}(\theta) \succeq 0, \ \mathcal{C}(\theta) \succeq 0, \ \mathcal{L}(\theta) \succeq 0 \text{ so that insertion loss and phase delay can be computed with the subject to the subject to$ realistic accuracy. These models serve as the foundation for understanding how power is dissipated and how phase velocity changes with frequency, ultimately affecting both amplitude and phase response in practical systems.

> Conductor losses dominate at lower microwave frequencies and become increasingly complex at higher ones due to the skin effect. The skin effect arises from electromagnetic induction: alternating currents generate magnetic

Table 4: Primary Loss Mechanisms in Microwave Transmission Lines

Mechanism	Physical Origin	Frequency Dependence	Dominant Range	Modeling Approach
Conductor loss	Finite σ , skin effect	$\propto \sqrt{\omega}$	Lowmid GHz	Surface impedance $R_s = \sqrt{\omega \mu/2\sigma}$
Surface roughness	Microscopic texture	$>\sqrt{\omega}$ growth	Midhigh GHz	$R_s\! imes\!F_r(\omega)$ correction
Dielectric loss	Polarization lag, $ an \delta$	Linearrelaxation	Wideband	Debye/Lorentz $\epsilon(\omega)$ model
Radiation loss	Field leakage, discontinuities	Geometry-specific	High GHz $/$ mmWave	Full-wave or Floquet envelope

fields that, in turn, oppose current flow deeper within the conductor, confining most of the current to a thin surface layer whose depth decreases as frequency increases. This skin depth is inversely proportional to the square root of both frequency and conductivity. As a result, the effective resistance per unit length of the conductor grows roughly with the square root of frequency. In smooth, idealized conductors, this relationship is well understood and can be modeled analytically using classical electrodynamics [20]. However, in real conductors, microscopic surface roughness significantly perturbs the current distribution. Peaks and valleys on the metal surface create locally enhanced current density, increasing ohmic dissipation. Rough surfaces can be represented using empirical correction factors or full-wave electromagnetic models that modify the boundary conditions at the metaldielectric interface. The effective surface resistance thereby exceeds the value predicted for a perfectly smooth surface, and the deviation grows with frequency as current confinement increases. phenomenon is particularly problematic in copper traces of printed circuit boards or in coaxial cables with electroplated inner conductors, where surface treatments, plating thickness, and mechanical processing can alter the roughness spectrum and, consequently, the loss behavior.

In addition to conductor losses, dielectric materials used to insulate and support conductors also contribute to microwave attenuation. Dielectric loss originates in two distinct mechanisms: conduction through imperfectly insulating materials and polarization relaxation within bound charge distributions. The conduction component is proportional to the materials conductivity and the square of the electric field magnitude, producing power dissipation that increases linearly with frequency. Polarization relaxation, on the other hand, arises because dipoles in the dielectric cannot instantaneously follow the oscillating electric field. This delay leads to a phase lag between the applied field and the induced polarization, which manifests as an effective imaginary component of the permittivity [21]. The magnitude of this component, often expressed through the loss tangent (tan), depends on both the molecular structure of the dielectric and temperature. In many engineering materials such as PTFE, polyethylene, or ceramic composites, the dielectric loss tangent is low and relatively constant up to tens of gigahertz, but even small values accumulate over long transmission paths. For higher-frequency operation or materials with significant dipolar dispersion, polarization relaxation can produce a strong frequency dependence that must be modeled using Debye or Lorentztype dispersion relations to preserve causality. These models ensure that the phase velocity and attenuation are consistent with the KramersKronig relations, which connect the real and imaginary parts of the permittivity.

Another, often less intuitive, source of loss is radiation. In bounded structures such as coaxial lines or rectangular waveguides, the electromagnetic fields are primarily confined to the cross-sectional region defined by the conductors. However, at discontinuities, bends, or transitions, the geometry can couple energy into higher-order or unbounded modes that carry power away from the main transmission path. In microstrip and coplanar lines, which are open structures with fields extending into air, radiation loss can also occur along straight sections due to imperfect confinement, particularly when the substrate thickness or permittivity causes partial leakage into surface-wave modes. These radiative losses are usually much smaller than conductor or dielectric losses in short, uniform lines but can become significant in high-frequency or high-density interconnects, where geometric dimensions are comparable to the wavelength. Careful design of the cross-section, ground return path, and surrounding environment is required to suppress such leakage.

To accurately predict the total insertion loss and phase delay across frequency, engineers construct distributedcircuit models that describe the line in terms of its per-unitlength parameters: resistance (R), inductance (L), conductance (G), and capacitance (C) [22]. Each of these parameters is frequency-dependent and interconnected. The resistance embodies the effects of skin depth and surface roughness; inductance reflects both magnetic energy storage and frequency-dependent current distribution; conductance models dielectric conduction losses; and capacitance represents energy stored in the electric field, modified by the dispersive permittivity of the dielectric. The combination of these parameters defines a complex propagation constant = + j, where represents attenuation and phase propagation per unit length. Causal frequency dependence means that and cannot vary independently; they are linked through the physical properties of the materials. Thus, any accurate model must maintain these relationships to ensure that computed time-domain responses do not exhibit nonphysical behavior such as negative group delay or energy gain.

Modern modeling techniques for microwave lines range from empirical curve fitting based on measured S-parameters to full electromagnetic simulations using numerical methods such as the finite element method (FEM)

or the method of moments (MoM). In empirical approaches, data are fitted to rational functions that enforce causality and passivity, ensuring stable time-domain behavior. In physics-based models, the cross-sectional geometry is meshed, and Maxwells equations are solved to extract the per-unit-length impedance and admittance matrices as functions of frequency. These matrices directly yield attenuation and phase constants that can be incorporated into circuit simulators. Hybrid models combine analytic approximations for simple geometries with correction factors derived from simulation or measurement to balance accuracy and computational cost [23]. In all cases, validation against experimental data is essential, since small deviations in surface finish, plating composition, or dielectric anisotropy can alter measured loss by several decibels per meter at gigahertz frequencies.

Practical design considerations further complicate the picture. Temperature variations change both metal conductivity and dielectric permittivity, leading to thermal drift in insertion loss and phase delay. Humidity or absorbed moisture in dielectric substrates can increase loss tangent and dielectric constant, degrading performance. Manufacturing tolerances in line width, dielectric thickness, and plating uniformity alter the effective impedance and field distribution, influencing both attenuation and dispersion. Engineers often mitigate these sensitivities by specifying high-purity conductors, low-loss dielectric materials, and controlled-impedance fabrication processes. Surface treatments such as chemical polishing or plating with smooth metals like silver can reduce roughnessinduced loss, though at increased cost. For extremely highfrequency applications, such as millimeter-wave interconnects above 60 GHz, even submicron surface variations and dielectric anisotropy become critical, and advanced characterization techniques like near-field scanning or terahertz time-domain spectroscopy are used to measure loss and dispersion.

At low frequencies, conductor losses dominate, scaling approximately with the square root of frequency due to the skin effect. As frequency rises, dielectric losses often become comparable or larger, especially when the dielectric exhibits relaxation near the operating band [24]. At even higher frequencies, radiation losses may become non-negligible as the wavelength approaches the physical dimensions of the structure. The net result is an attenuation curve that typically increases monotonically with frequency but may exhibit slope changes reflecting transitions between dominant mechanisms. Phase delay, meanwhile, varies due to dispersion introduced by both the conductor boundary conditions and the dielectric polarization response, producing frequency-dependent group velocity. In communication and radar systems, these variations can distort modulated signals or shift timing, making accurate prediction and compensation essential.

Dielectric loss scales with the loss tangent and may vary with temperature, electric field, and moisture content, all

of which drift over a product lifetime.

$$\delta(\omega) = \sqrt{\frac{2}{\mu\sigma\omega}}, \quad R_s(\omega) = \sqrt{\frac{\omega\mu}{2\sigma}}$$

Surface roughness can be captured by multiplicative corrections to $R_s(\omega)$ or by effective medium approaches. These corrections couple frequency, geometry, and fabrication processes, linking line attenuation not just to material purity but to the statistical distribution of surface features. Dielectric behavior often follows relaxation models that interpolate between static and optical permittivities, with conductivity providing a low-frequency loss floor. The real and imaginary parts of permittivity remain causally related, and any fitted model must preserve that analytic structure to avoid nonphysical time-domain responses.

$$\epsilon(\omega) = \epsilon_{\infty} + \sum_{k=1}^{N} \frac{\Delta \epsilon_k}{1 + j\omega \tau_k} + \frac{\sigma}{j\omega}$$

For canonical planar lines, effective permittivity connects to field confinement between the dielectric and air [25]. Quasi-static formulas relate geometry to capacitance and hence to phase velocity, while dispersion enters through frequency-dependent field penetration and substrate anisotropy or metal thickness. These dependencies propagate into $Z_0(\omega)$ and $\beta(\omega)$, tying phase noise transfer and group delay flatness directly to fabrication and material control. In coupled lines, even weak frequency dependence of coupling coefficients can shift passbands and stopbands of directional couplers, altering isolation and directivity in ways that only line-aware models reveal.

$$Z_0(\omega) \approx \sqrt{\frac{L'(\omega)}{C'(\omega)}}, \quad \beta(\omega) \approx \omega \sqrt{L'(\omega)C'(\omega)}, \quad \epsilon_{\rm eff}(\omega) = \left(\frac{c\beta(\omega)}{\omega}\right)$$

Radiation losses become prominent when the line dimensions approach the substrate wavelength or when discontinuities excite higher-order or leaky modes. Periodic loading used for dispersion engineering can intentionally create stopbands and slow-wave regions but also risks radiation if band edges intersect the light line. Modeling these effects within a transmission-line-like envelope uses Floquet expansions and Bloch impedances that generalize Z_0 to periodic structures. The key point remains that loss and dispersion are joint properties of geometry and materials, and that the transmission line abstraction can carry enough physics to predict both with the fidelity required for design under reliability constraints.

$$Z_B(\omega,k) = \sqrt{\frac{Z_{\rm cell}(\omega,k)}{Y_{\rm cell}(\omega,k)}}, \quad \cos\left(ka\right) = \frac{A_{\rm cell}(\omega) + D_{\rm cell}(\omega)}{2}$$

Electro-Thermal Coupling and Power-Handling Reliability

At elevated power, microwave lines and passive networks experience self-heating due to conductor and dielectric

Table 5: Frequency-Dependent Line Parameters and Derived Quantities

Quantity	Relation / Definition	Physical Meaning	Influences	Notes
$\delta(\omega)$	$\sqrt{2/(\mu\sigma\omega)}$	Skin depth	σ, ω	Shrinks with $\sqrt{\omega}$
$Z_0(\omega)$	$\sqrt{L'(\omega)/C'(\omega)}$	Characteristic impedance	Geometry, ϵ_{eff}	Dispersion-sensitive
$eta(\omega)$	$\omega \sqrt{L'C'}$	Phase constant	L^\prime , C^\prime , material	Drives delay, phase noise
$\epsilon_{\sf eff}(\omega)$	$(c\beta/\omega)^2$	Effective permittivity	Field confinement	Links phase to material
$\epsilon(\omega)$	$\epsilon_{\infty} + \sum \frac{\Delta \epsilon_k}{1 + j\omega \tau_k} + \frac{\sigma}{j\omega}$	Complex permittivity	Relaxation, conductivity	Causal dielectric model

Table 6: Design Sensitivities and Environmental Influences

Factor	Affected Parameter	Trend / Effect	Mitigation	Impact on Performance
Temperature	$\sigma(T), \epsilon(T)$	$\downarrow \sigma, \uparrow \epsilon$	Thermal control, materials	Loss, phase drift
Humidity / Moisture	$\tan \delta$, ϵ_r	Increases loss	Hermetic / low-absorption dielectrics	Amplitude degradation
Fabrication tolerance	Line width, thickness	Alters Z_0 , eta	Tight process control	Impedance mismatch
Surface finish	Roughness spectrum	Raises R_s	Polishing, smooth plating	Attenuation rise
Anisotropy / weave	ϵ_{eff} modulation	Skew, dispersion	Spread-glass selection	Timing, isolation drift

dissipation. The resulting temperature rise feeds back into material parameters such as conductivity and loss tangent, modifying $R(\omega)$ and $G(\omega)$ and shifting $Z_0(\omega)$ and $\gamma(\omega)$. This feedback creates amplitude-dependent insertion loss and phase delay, as well as potential thermal runaway in regions of high current density or electric field concentration. Predicting safe operating regions thus requires a coupled electro-thermal model that captures steady-state and transient heating, boundary conditions to heat sinks, and thermal conductivities and capacities of the stack. [26]

$$\nabla \cdot \left(\kappa(\mathbf{r},T)\nabla T(\mathbf{r})\right) + q(\mathbf{r}) = 0, \quad q(\mathbf{r}) = \frac{1}{2}\Re\{\mathbf{J}(\mathbf{r})\cdot\mathbf{E}^*(\mathbf{r})\}$$

Temperature-dependent conductivity and permittivity can be linearized for small excursions or treated with Arrhenius-type laws for processes such as electromigration and dielectric breakdown precursors. When thermal gradients are strong, the per-unit-length parameters become spatially varying, and the line behaves as an inhomogeneous medium. Under sinusoidal excitation, this translates into an effective propagation constant that is the solution of a boundary-value problem with coefficients depending on the unknown temperature field. To maintain tractability, reduced-order models approximate the dependence by sensitivity coefficients around an operating point, enabling fast prediction of hot spots and lifetime under arbitrary drive waveforms.

$$\sigma(T) = \sigma_0 \, \exp\!\left(-\frac{E_a}{k_B} \left(\frac{1}{T} - \frac{1}{T_0}\right)\right), \quad \epsilon''(T) \approx \epsilon_0'' + \eta \, (T - T_0)$$

Electromigration risk associates with current density and temperature via empirical laws that predict mean time to failure. Transmission line theory localizes the maxima of current density near bends, tapers, and via transitions where characteristic impedance changes abruptly. By correlating standing-wave patterns with electromagnetic

energy density and current crowding, one can place design rules on bend radius, via fields, and matching quality that reduce stress. The same reasoning applies to dielectric reliability, where peak electric fields near edges and in thin gaps increase the probability of partial discharge and progressive degradation under cyclic drive.

$$\mathsf{MTTF} \approx A \, J^{-n} \, \exp\!\left(\frac{E_a}{k_B T}\right)$$

Self-generated intermodulation in ostensibly passive structures, often labeled as nonlinear passive intermodulation, arises from microscopic nonlinearity at imperfect interfaces and contacts **71**. Local heating modulates contact conditions and microscopic conduction paths, generating low-level spectral products whose levels depend on both average and peak power and on the spatial pattern of current flow. Since transmission line mismatches control local field amplitudes, reducing standing waves by improved impedance matching and smoother discontinuities directly lowers such intermodulation levels. Electro-thermal simulations that map hot spot distributions to local nonlinearity parameters become predictive when anchored by line-based power flow.

$$P_{\mathsf{IMD}} \propto \left(\int_{\mathsf{surface}} |J_t(\mathbf{r})|^m \, dS
ight), \quad m > 2$$

Variability, Uncertainty, and Yield

Manufacturing variability and environmental drift perturb geometry and materials, thereby altering per-unit-length parameters and the network responses they generate. Yield-driven design treats these perturbations as random variables and asks for the probability that specifications are met over the relevant ensemble. Transmission line theory enables sensitivity analysis by differentiating reflection and transmission with respect to geometric and material parameters in closed or semi-closed form, which guides both nominal optimization and the placement of margin where it is most effective. The chain from random

variations to performance metrics runs through $\gamma(\omega)$ and $Z_0(\omega)$ to S-parameters and time-domain waveforms, and can be approximated with polynomial chaos or other spectral expansions that remain faithful to the underlying physics.

$$\theta \sim \rho(\theta),$$

$$\mathcal{Y}(\theta) = \Phi(\gamma(\omega; \theta), Z_0(\omega; \theta)),$$

$$\text{Yield} = \Pr{\mathcal{Y}(\theta) \in \mathcal{S}}$$
 (12)

Local linearizations provide first-order estimates of variance in outputs, while higher-order expansions capture nonlinear dependence near resonant conditions where sensitivities blow up [27]. Structural reliability methods approximate rare-event probabilities by locating design points in the space of random inputs where constraints are nearest to violation in a suitable metric. The mapping supplied by line theory simplifies these computations by providing analytic gradients and by ensuring that constraints such as passivity remain enforced across perturbations, avoiding unphysical excursions in the model that would otherwise corrupt probability estimates.

$$\operatorname{Var}[\mathcal{Y}] \approx \nabla_{\theta} \mathcal{Y}(\bar{\theta})^{\top} \operatorname{Cov}[\theta] \nabla_{\theta} \mathcal{Y}(\bar{\theta})$$

Worst-case design complements probabilistic yield with deterministic bounds that cover specified parameter boxes. By expressing the reflection and insertion loss as monotone or quasi-convex functions of underlying parameters over certain frequency windows, one derives efficiently computable certificates that the design meets limits under all specified variations. When functions are not monotone, envelope constructions built from extremal evaluations on corners and selected interior points often suffice. The link to reliability is immediate: designs with provable bounds on mismatch and loss under tolerance stacks will also show bounded localized fields, reducing the risk of runaway heating and degradation.

$$\max_{\theta \in \Theta} \sup_{\omega \in \Omega} |\Gamma_{\text{in}}(\omega; \theta)| \le \Gamma_{\text{max}}$$

A key role for line theory in uncertainty quantification is model reduction. High-fidelity field solvers produce frequency responses rich in detail but expensive to sample. Model order reduction that preserves passivity and matches moments of the transfer function around relevant expansion points yields surrogates that are both fast and stable in stochastic loops. Parameterized macromodels trained against variations in geometry and materials then interpolate the response across the tolerance space [28]. These surrogates, expressed directly in terms of transmission line descriptors, allow thousands of Monte Carlo samples to be evaluated quickly, while retaining enough physics to predict shifts in group delay and phase that drive system-level impairments.

$$H(\omega, \theta) \approx \sum_{k=1}^{K} \frac{r_k(\theta)}{j\omega - p_k(\theta)} + d(\theta)$$

Measurement, Calibration, and Diagnostics

Measurement accuracy at microwave frequencies depends on calibration schemes that remove systematic errors due to cables, adapters, and fixtures. Transmission line standards anchor these schemes by providing known phase and magnitude responses over frequency. In thru-reflect-line strategies, a line of known length and characteristic impedance sets a phase reference, while reflect standards bound magnitude errors. Error-box models place two unknown networks around the device under test; solving for these boxes using line-based standards reveals the intrinsic device S-parameters in a way consistent with power conservation and reciprocity where appropriate.

$$\begin{bmatrix} \mathbf{b} \\ \mathbf{a} \end{bmatrix}_{\text{meas}} = \mathbf{E}_2(\omega) \begin{bmatrix} \mathbf{b} \\ \mathbf{a} \end{bmatrix}_{\text{DUT}} \mathbf{E}_1(\omega),$$

solve $\mathbf{E}_1, \mathbf{E}_2$ using line and reflect standards (13)

Time-domain reflectometry interprets the response to a step or pulse as a spatial map of impedance. By treating the structure as a line with spatially varying characteristic impedance, reflections from each location superpose with delays proportional to twice the travel time. Deconvolution of the instruments source and receiver responses yields an estimate of the local reflection coefficient as a function of distance, revealing discontinuities, voids, or material inhomogeneities. In dispersive lines, proper inversion accounts for frequency-dependent phase velocity to avoid smearing localized features; such inversions are straightforward when dispersion derives from a rational model of $\beta(\omega)$.

$$\Gamma(z) pprox \mathcal{F}^{-1} \left\{ rac{V_{
m meas}(\omega)}{V_{
m src}(\omega)} \, e^{2j\beta(\omega)z}
ight\}$$

De-embedding techniques for fixtures combine line theory with matrix algebra. When a symmetrical two-line through connection is available, one solves for the fixture halves by matrix square roots in an appropriate network representation, then inverts these to extract the device response [29]. Stability and numerical conditioning benefit from power-wave normalization and from ensuring that the fixture models remain passive. The same methodology supports in-situ monitoring, where line segments integrated into a product serve as permanent witnesses whose scattering parameters reflect the health of interconnects and device terminations over time, providing early warning of degradation before functionality is compromised.

$$\mathbf{S}_{\text{DUT}} = \mathbf{S}_{\text{fix}}^{-1} \star \mathbf{S}_{\text{thru}} \star \mathbf{S}_{\text{fix}}^{-1}$$

Instrumentation limits also tie back to line behavior. Connector repeatability, cable flexing, and temperature drift manifest as phase and magnitude errors that scale with line length and with the sensitivity of $Z_0(\omega)$ and $\gamma(\omega)$ to environmental conditions. Designing measurement paths with controlled impedance, minimal discontinuities, and thermal stabilization is thus as much a transmission line problem as a mechanical one. The goal is to ensure that calibration remains valid across the time and environmental variations relevant to the target application, enabling measurements that feed reliably into performance and lifetime predictions.

Dispersion Engineering and Distributed Synthesis

Engineered dispersion reshapes microwave behavior by tailoring the frequency dependence of phase velocity and characteristic impedance. Periodically loaded lines, composite right/left-handed structures, and slow-wave geometries use unit cells that impart desired group delay profiles, realizing wideband matching sections, compact resonators, and phase shifters with reduced size. Transmission line theory provides the language of Bloch waves and cell transfer matrices, translating geometric sequencing into band structures whose passbands and stopbands control energy flow. Reliability enters as dispersion affects energy density localization at band edges, which can concentrate fields and trigger thermal or dielectric stress if not managed carefully. [30]

$$\cos\left(\beta(\omega)a\right) = \frac{A_{\rm cell}(\omega) + D_{\rm cell}(\omega)}{2}, \quad v_g(\omega) = \frac{d\omega}{d\beta(\omega)}$$

Distributed synthesis treats target impedances or phase responses as goals to be approximated by cascades of lines and stubs whose ABCD matrices multiply to match the desired function across a specified band. Rational approximation theorems assure that such realizations exist subject to passivity and causality, and constructive methods map poles and zeros to physical lengths and characteristic impedances. Sensitivity analysis within this framework identifies which segments dominate error budgets, focusing tolerance control where it matters most. Electro-thermal corrections can be layered on top by treating temperature dependence as a small perturbation that shifts the effective electrical lengths and impedances, allowing rapid recalculation of performance at elevated power.

$$\begin{bmatrix} A & B \\ C & D \end{bmatrix}_{\text{target}}(\omega) \approx \prod_{k=1}^{N} \begin{bmatrix} \cosh(\gamma_k(\omega)l_k) & Z_{0k}(\omega)\sinh(\gamma_k(\omega)l_k) \\ \sinh(\gamma_k(\omega)l_k)/Z_{0k}(\omega) & \cosh(\gamma_k(\omega)l_k) \end{bmatrix}$$

$$\begin{array}{c} Z_{0k}(\omega)\sinh(\gamma_k(\omega)l_k) \\ \cosh(\gamma_k(\omega)l_k) \\ \cosh(\gamma_k(\omega)l_k) & \text{embedding impedance in both the intended oscillation} \\ \text{(14)} & \text{onsters set these impedances with phase that varies over} \end{array}$$

Directional couplers and hybrids illustrate how coupling coefficients and phase relations hinge on dispersion [31]. Even modest frequency dependence in coupling leads to amplitude and phase imbalance across the band, degrading isolation and return loss. By embedding the coupled-line equations into the design loop and ensuring that

per-unit-length coupling parameters remain within ranges compatible with fabrication, one can optimize directivity and achieve flatter coupling over bandwidths that would otherwise be inaccessible. The same strategy extends to filters realized with coupled resonators, where modal dispersion aligns with passband ripple and stopband attenuation in ways that line-aware synthesis can exploit.

$$\kappa(\omega) = \frac{\beta_{\rm even}(\omega) - \beta_{\rm odd}(\omega)}{\beta_{\rm even}(\omega) + \beta_{\rm odd}(\omega)}, \quad S_{31}(\omega) \approx j\sqrt{\kappa(\omega)} \, e^{-j\phi(\omega)}$$

System Architectures and Embedded Interconnect Effects

Microwave systems integrate active and passive subsystems through interconnects that are themselves distributed networks. The interplay between device I/O impedances and line sections shapes gain, noise, linearity, and spectral purity. Noise matching differs from power matching, and the impedance presented to a low-noise amplifier or mixer must honor both noise parameters and stability constraints across band edges and out-of-band regions where oscillations may occur. Lines not only transform impedances but also introduce delays that couple to feedback loops, altering phase margins and the positions of spurious responses.

$$\Gamma_{\text{in}}(\omega) = S_{11}(\omega) + \frac{S_{12}(\omega)S_{21}(\omega)\Gamma_L(\omega)e^{-2\gamma(\omega)l}}{1 - S_{22}(\omega)\Gamma_L(\omega)e^{-2\gamma(\omega)l}}$$

Power amplifier matching networks exemplify the dual role of lines in performance and reliability. Load-pull contours in the complex plane translate via transmission lines into spatial distributions of voltage and current on the board or in the package. The resulting field and temperature maps determine peak stress, median temperatures, and cycling amplitudes that govern lifetime under typical modulation. When bias networks are realized with high-impedance lines to isolate RF from DC, their resonances and leakage paths must be modeled to avoid parametric instabilities and undesired modulation of supply rails [32]. The design objective becomes a multi-criteria optimization over efficiency, linearity, stability, and thermal headroom.

$$\eta_{\mathrm{PA}} = \frac{P_{\mathrm{out}}}{P_{\mathrm{DC}}} = \frac{|V^+|^2 \Re\{Y_0\}}{V_{\mathrm{DD}} I_{\mathrm{DD}}}$$

 l_k) oscillator phase noise and frequency pulling depend on embedding impedance in both the intended oscillation band and at harmonics. Transmission line stubs and resonators set those impedances with phase that varies over temperature and bias. Reliability considerations arise because drift in line parameters shifts the oscillation condition, potentially increasing close-in noise or generating spurs. Modeling the tank and feedback paths as distributed networks reveals the sensitivity of loop gain and Barkhausen phase to geometry and materials, quantifying

how much drift can be tolerated before performance falls below target.

$$L(f_m) \propto \frac{Fk_BT}{2P_{\rm sig}} \left(\frac{\partial \phi}{\partial \omega}\right)^2, \quad \frac{\partial \phi}{\partial \omega} \approx \frac{d}{d\omega} \arg\left(H_{\rm loop}(\omega)\right)$$

Millimeter-wave packaging intensifies all of these effects. Short wavelengths exaggerate discontinuity reactances, and interconnect parasitics in transitions between dies, interposers, and boards become dominant. Transmission line segments inside packages act as resonators and coupling paths, and their losses and dispersion depend sensitively on metallization thickness, surface condition, and dielectric anisotropy. Reliability risks include delamination and crack growth accelerated by thermal gradients driven by localized dissipation. Embedding transmission line-aware constraints at the package levelcontrolling electrical lengths, enforcing impedance continuity, and distributing currents to avoid hot spotsimproves both initial performance and long-term stability. [33]

From Field Solvers to Circuit Models: Extraction and Macromodeling

Full-wave solvers resolve Maxwells equations on the geometries of interest and return port responses and field distributions. To make these results useful at the circuit and system level, one must extract per-unit-length parameters and macromodels that summarize the distributed behavior. For uniform or piecewise uniform structures, modal analysis identifies dominant modes and their propagation constants; projecting fields onto these modes yields frequency-dependent R, L, G, and C that feed directly into transmission line models. For more complex structures, rational approximation of the port responses produces state-space models that can be cascaded and embedded in time-domain simulations with guaranteed passivity.

$$\begin{bmatrix} \dot{\mathbf{x}} \\ \mathbf{y} \end{bmatrix} = \begin{bmatrix} \mathbf{A} & \mathbf{B} \\ \mathbf{C} & \mathbf{D} \end{bmatrix} \begin{bmatrix} \mathbf{x} \\ \mathbf{u} \end{bmatrix}, \quad \mathbf{H}(\omega) = \mathbf{D} + \mathbf{C}(j\omega\mathbf{I} - \mathbf{A})^{-1}\mathbf{B}$$

Passivity enforcement plays a decisive role in reliability-oriented verification. If a macromodel violates passivity, simulations can produce nonphysical energy generation that hides potential instabilities or fabricates false margins. Projection-based methods coupled with Hamiltonian matrix tests adjust residues and poles to restore passivity without significantly distorting the fit. Causality checks using Hilbert transforms ensure that time-domain responses do not anticipate inputs. The combination yields compact models that track insertion loss, group delay, and reflection over frequency while remaining robust under composition in larger networks.

$$\mathbf{W}^H\mathbf{J}\mathbf{W}\succeq 0,\quad \text{with } \mathbf{J}=\begin{bmatrix}0 & I\\ -I & 0\end{bmatrix}$$

Parameterization with respect to geometry and materials supports design exploration and uncertainty quantification [34]. Reduced bases for fields or for port responses enable efficient updates as dimensions or permittivities change, avoiding full re-solves. The resulting parametric macromodels serve as surrogates in optimization loops that target return loss, insertion loss, group delay, or power division error while simultaneously constraining field maxima connected to reliability. Because transmission line theory supplies the structure of the models, even aggressive reduction can preserve the critical relationships between energy storage, propagation, and dissipation.

$$\mathbf{H}(\omega, \theta) \approx \sum_{i=1}^{M} \psi_i(\theta) \, \mathbf{H}_i(\omega)$$

Design-for-Reliability Rules from Transmission Line Insight

Rules that improve lifetime without sacrificing performance often distill to constraints on impedance continuity, current density distribution, and thermal pathways, all of which are line-theoretic quantities. Smooth impedance transitions reduce standing waves and peak fields; adequate conductor thickness and radius of curvature distribute current and lower local Joule heating; controlled coupling prevents unintended resonances and beat patterns that localize energy. Transmission line calculations quantify how much smoothing or thickness increase is necessary to achieve target reductions in peak field or temperature, turning qualitative rules into verifiable specifications.

$$\max_{z \in [0,l]} |I(z)| \leq I_{\max}, \quad I(z) = \frac{V^+}{Z_0} \, e^{-\gamma z} - \frac{V^-}{Z_0} \, e^{\gamma z}$$

Thermal vias and heat spreaders can be placed where line theory predicts current and field maxima, not merely where board convenience suggests. Likewise, bias decoupling networks designed as high-impedance lines at RF must be verified for spurious passbands introduced by parasitics; impedance plots that include dispersion and loss ensure that no unintended resonance falls near strong spectral components of the drive. Environmental sealing against moisture protects dielectric properties; since dielectric loss contributes directly to heating under standing waves, maintaining stable permittivity and low loss tangent over lifetime directly increases margins against runaway conditions.

$$R_{\theta, {\rm eff}} pprox \left([35] \int_{\Omega} rac{\phi^2({f r})}{\kappa({f r})} \, d{f r}
ight)^{-1},$$
 $\phi({f r})$ normalized heat flow potential (15)

Design signoff combines electrical and thermal checks with statistical margins. Transmission line models evaluated over corner cases and Monte Carlo ensembles provide

distributions of reflection, insertion loss, and group delay, which in turn map to distributions of current density and temperature rise. Acceptance criteria then become probabilities that these derived quantities remain below limits, providing a direct line from network specifications to lifetime metrics. Because the foundational models are based on energy and power flow along lines, the resulting assurances carry physical meaning rather than purely empirical correlation.

$$\Pr\left\{\max_{z}|E(z)| \le E_{\mathsf{lim}} \ \cap \ \max_{z}T(z) \le T_{\mathsf{lim}}\right\} \ge 99.9\%$$

Conclusion

Transmission line theory provides the natural coordinate system for both the performance and the reliability of microwave circuits, serving as a bridge between electromagnetic field behavior and the lumped or distributed circuit representations used in design. By expressing electromagnetic phenomena in terms of per-unit-length parametersresistance, inductance, conductance, and capacitancealong with propagation constants and characteristic impedances, the theory distills Maxwells equations into a form that engineers can manipulate with analytical precision. Each infinitesimal segment of a line carries the essence of the field equations, yet the collective behavior across an entire structure can be modeled through linear networks that compose neatly and predictably. This abstraction condenses complex physics into relationships that admit stable macromodeling, preserving causality and passivity, and it aligns directly with how power and energy flow through real hardware. Transmission line models therefore do more than describe voltage and current; they embody the distributed nature of fields, losses, and reflections, offering a unified framework that links design intent with measurable performance.

Through this framework, matching and stability strategies acquire a more complete physical meaning. Rather than treating interconnects as mere conduits, transmission line theory recognizes them as active participants in feedback loops and resonant behavior [36]. The impedance presented by a line section interacts with source and load impedances in ways that can either reinforce or suppress oscillations, depending on length, termination, and frequency. Consequently, achieving stability in amplifiers or oscillators becomes not just a matter of biasing and gain control but also of ensuring that the distributed paths between components are electrically compatible. When interconnects are designed as integral parts of the circuits energy flow, the risk of parasitic feedback diminishes, and the overall system becomes more predictable across operating conditions. This principle extends naturally to the synthesis of microwave components such as couplers, filters, combiners, and bias networks, where the geometry and materials of transmission lines define the desired transfer functions. Each of these devices can be seen as a specific manipulation of guided wave behavior, and their robustness across frequency, temperature, and manufacturing variability is a direct outcome of designing from first principles within the transmission line framework.

Incorporating the physics of conductors and dielectrics further enriches the theorys predictive power. Real materials introduce frequency-dependent losses and dispersion, which alter signal phase and amplitude in ways that simple idealized models cannot capture. By embedding these effects into the per-unit-length parameters, one can produce causal models that remain valid from DC through millimeter-wave frequencies. The inclusion of skin effect, surface roughness, and dielectric relaxation ensures that computed S-parameters or time-domain responses align closely with what is measured in practice. Moreover, at high power levels, electro-thermal coupling becomes significant: resistive heating modifies conductivity and permittivity, changing propagation constants and thereby shifting impedance or phase [37]. Transmission line models that account for such coupling can predict where hot spots will form, where field maxima will concentrate, and how these conditions evolve over time. This predictive capacity enables designers to foresee long-term degradation mechanisms, such as electromigration in conductors or dielectric breakdown, and to mitigate them through geometric optimization or material selection before hardware is ever built.

Reliability analysis gains additional rigor when uncertainty quantification is anchored in transmission line descriptors. Because line parameters respond systematically to variations in dimensions, material properties, and environment, sensitivities can be computed with respect to each source of uncertainty. These sensitivities, in turn, support yield estimation and worst-case analysis, translating electrical specifications into statistical assurances of lifetime performance. For instance, a designer may evaluate how a $\pm 5\%$ tolerance in substrate thickness affects characteristic impedance or how humidity alters dielectric constant over time. The resulting variations in return loss or phase delay can be propagated through a system-level model to predict end-of-life performance margins. Such quantitative links between geometry, materials, and function allow organizations to define manufacturing windows that preserve both yield and reliability. In essence, the same mathematical structure that supports circuit synthesis also enables robust design verification under uncertainty, tying together performance and durability within one theoretical framework.

Instrumentation and diagnostics rely on the same theoretical foundation to validate models and correct designs [38]. Measurement techniques such as vector network analysis and time-domain reflectometry depend fundamentally on the interpretation of incident and reflected waves along transmission lines. Calibration standardsopen, short, load, and throughare defined in terms of known line parameters, ensuring that measured S-parameters reflect the behavior of the device under test rather than that of the measurement fixtures. When a discontinuity appears in a time-

domain trace, it is transmission line theory that allows the engineer to map that reflection back to a specific physical location and to infer the nature of the defectwhether a gap in solder, a via stub, or a dielectric void. In this way, laboratory measurements become an extension of the theoretical framework, closing the loop between analysis, fabrication, and validation. The models remain trustworthy precisely because the same mathematics governs both the predicted and the measured behavior, enabling accurate de-embedding and rapid correction of design flaws.

The deeper lesson is that when transmission line theory is elevated from a computational convenience to a design philosophy, it transforms the way microwave hardware is conceived and realized. Instead of being an afterthought applied only during impedance matching, it becomes the guiding principle from the earliest sketches of topology through final qualification testing. Designers begin to think in terms of field distributions rather than mere node voltages, arranging conductors and dielectrics to distribute current and energy smoothly. The resulting circuits exhibit low mismatch, low loss, and highly predictable phase response, even under environmental stress. Because energy flow is guided rather than confined, localized thermal or electrical stress is reduced, extending component lifetime and improving mean time to failure. Efficiency improves as standing waves diminish, bandwidth widens because dispersion is managed rather than ignored, and stability margins increase as parasitic coupling paths are brought under control. [39]

Conflict of interest

Authors state no conflict of interest.

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